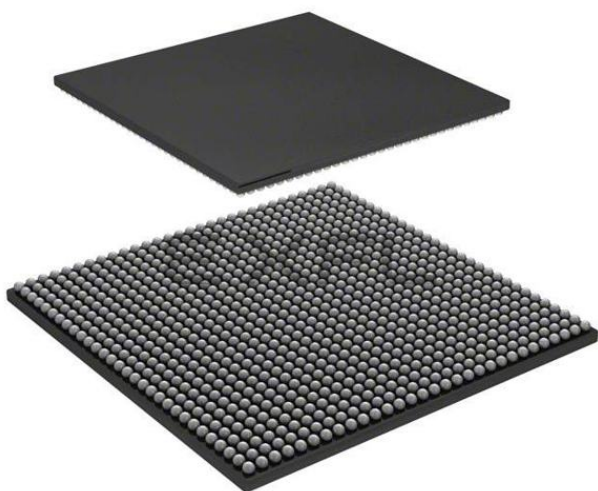




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Understanding Embedded - FPGAs (Field Programmable Gate Array)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details

Product Status	Obsolete
Number of LABs/CLBs	11519
Number of Logic Elements/Cells	147443
Total RAM Bits	4939776
Number of I/O	540
Number of Gates	-
Voltage - Supply	1.14V ~ 1.26V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 85°C (TJ)
Package / Case	900-BBGA
Supplier Device Package	900-FBGA (31x31)
Purchase URL	https://www.e-xfl.com/product-detail/xilinx/xc6slx150t-4fgg900c

Quiescent Current

Typical values for quiescent supply current are specified at nominal voltage, 25°C junction temperatures (T_j). Quiescent supply current is specified by speed grade for Spartan-6 devices. Xilinx recommends analyzing static power consumption using the XPOWER™ Estimator (XPE) tool (download at <http://www.xilinx.com/power>) for conditions other than those specified in Table 5.

Table 5: Typical Quiescent Supply Current

Symbol	Description	Device	Speed Grade				Units
			-3	-3N	-2	-1L	
I_{CCINTQ}	Quiescent V_{CCINT} supply current	LX4	4.0	4.0	4.0	2.4	mA
		LX9	4.0	4.0	4.0	2.4	mA
		LX16	6.0	6.0	6.0	4.0	mA
		LX25	11.0	11.0	11.0	6.6	mA
		LX25T	11.0	11.0	11.0	N/A	mA
		LX45	15.0	15.0	15.0	9.0	mA
		LX45T	15.0	15.0	15.0	N/A	mA
		LX75	29.0	29.0	29.0	17.4	mA
		LX75T	29.0	29.0	29.0	N/A	mA
		LX100	36.0	36.0	36.0	21.6	mA
		LX100T	36.0	36.0	36.0	N/A	mA
		LX150	51.0	51.0	51.0	31.0	mA
		LX150T	51.0	51.0	51.0	N/A	mA
I_{CCOQ}	Quiescent V_{CCO} supply current	LX4	1.0	1.0	1.0	1.0	mA
		LX9	1.0	1.0	1.0	1.0	mA
		LX16	2.0	2.0	2.0	2.0	mA
		LX25	2.0	2.0	2.0	2.0	mA
		LX25T	2.0	2.0	2.0	N/A	mA
		LX45	3.0	3.0	3.0	3.0	mA
		LX45T	3.0	3.0	3.0	N/A	mA
		LX75	4.0	4.0	4.0	4.0	mA
		LX75T	4.0	4.0	4.0	N/A	mA
		LX100	5.0	5.0	5.0	5.0	mA
		LX100T	5.0	5.0	5.0	N/A	mA
		LX150	7.0	7.0	7.0	7.0	mA
		LX150T	7.0	7.0	7.0	N/A	mA

SelectIO™ Interface DC Input and Output Levels

Table 7: Recommended Operating Conditions for User I/Os Using Single-Ended Standards

I/O Standard	V _{CCO} for Drivers ⁽¹⁾			V _{REF} for Inputs		
	V, Min	V, Nom	V, Max	V, Min	V, Nom	V, Max
LVTTTL	3.0	3.3	3.45	V _{REF} is not used for these I/O standards		
LVC MOS33	3.0	3.3	3.45			
LVC MOS25	2.3	2.5	2.7			
LVC MOS18	1.65	1.8	1.95			
LVC MOS18_JEDEC	1.65	1.8	1.95			
LVC MOS15	1.4	1.5	1.6			
LVC MOS15_JEDEC	1.4	1.5	1.6			
LVC MOS12	1.1	1.2	1.3			
LVC MOS12_JEDEC	1.1	1.2	1.3			
PCI33_3 ⁽²⁾	3.0	3.3	3.45			
PCI66_3 ⁽²⁾	3.0	3.3	3.45			
I2C	2.7	3.0	3.45			
SMBUS	2.7	3.0	3.45			
SDIO	3.0	3.3	3.45			
MOBILE_DDR	1.7	1.8	1.9			
HSTL_I	1.4	1.5	1.6	0.68	0.75	0.9
HSTL_II	1.4	1.5	1.6	0.68	0.75	0.9
HSTL_III	1.4	1.5	1.6	–	0.9	–
HSTL_I_18	1.7	1.8	1.9	0.8	0.9	1.1
HSTL_II_18	1.7	1.8	1.9	–	0.9	–
HSTL_III_18	1.7	1.8	1.9	–	1.1	–
SSTL3_I	3.0	3.3	3.45	1.3	1.5	1.7
SSTL3_II	3.0	3.3	3.45	1.3	1.5	1.7
SSTL2_I	2.3	2.5	2.7	1.13	1.25	1.38
SSTL2_II	2.3	2.5	2.7	1.13	1.25	1.38
SSTL18_I	1.7	1.8	1.9	0.833	0.9	0.969
SSTL18_II	1.7	1.8	1.9	0.833	0.9	0.969
SSTL15_II	1.425	1.5	1.575	0.69	0.75	0.81

Notes:

1. V_{CCO} range required when using I/O standard for an output. Also required for MOBILE_DDR, PCI33_3, LVC MOS18_JEDEC, LVC MOS15_JEDEC, and LVC MOS12_JEDEC inputs, and for LVC MOS25 inputs when V_{CCAUX} = 3.3V.
2. For PCI systems, the transmitter and receiver should have common supplies for V_{CCO}.

In Table 9 and Table 10, values for V_{IL} and V_{IH} are recommended input voltages. Values for I_{OL} and I_{OH} are guaranteed over the recommended operating conditions at the V_{OL} and V_{OH} test points. Only selected standards are tested. These are chosen to ensure that all standards meet their specifications. The selected standards are tested at a minimum V_{CCO} with the respective V_{OL} and V_{OH} voltage levels shown. Other standards are sample tested.

Table 9: Single-Ended I/O Standard DC Input and Output Levels

I/O Standard	V_{IL}		V_{IH}		V_{OL}	V_{OH}	I_{OL}	I_{OH}
	V, Min	V, Max	V, Min	V, Max	V, Max	V, Min	mA	mA
LVTTTL	−0.5	0.8	2.0	4.1	0.4	2.4	Note 2	Note 2
LVC MOS33	−0.5	0.8	2.0	4.1	0.4	$V_{CCO} - 0.4$	Note 2	Note 2
LVC MOS25	−0.5	0.7	1.7	4.1	0.4	$V_{CCO} - 0.4$	Note 2	Note 2
LVC MOS18	−0.5	0.38	0.8	4.1	0.45	$V_{CCO} - 0.45$	Note 2	Note 2
LVC MOS18 (−1L)	−0.5	0.33	0.71	4.1	0.45	$V_{CCO} - 0.45$	Note 2	Note 2
LVC MOS18_JEDEC	−0.5	35% V_{CCO}	65% V_{CCO}	4.1	0.45	$V_{CCO} - 0.45$	Note 2	Note 2
LVC MOS15	−0.5	0.38	0.8	4.1	25% V_{CCO}	75% V_{CCO}	Note 3	Note 3
LVC MOS15 (−1L)	−0.5	0.33	0.71	4.1	25% V_{CCO}	75% V_{CCO}	Note 3	Note 3
LVC MOS15_JEDEC	−0.5	35% V_{CCO}	65% V_{CCO}	4.1	25% V_{CCO}	75% V_{CCO}	Note 3	Note 3
LVC MOS12	−0.5	0.38	0.8	4.1	0.4	$V_{CCO} - 0.4$	Note 4	Note 4
LVC MOS12 (−1L)	−0.5	0.33	0.71	4.1	0.4	$V_{CCO} - 0.4$	Note 4	Note 4
LVC MOS12_JEDEC	−0.5	35% V_{CCO}	65% V_{CCO}	4.1	0.4	$V_{CCO} - 0.4$	Note 4	Note 4
PCI33_3	−0.5	30% V_{CCO}	50% V_{CCO}	$V_{CCO} + 0.5$	10% V_{CCO}	90% V_{CCO}	1.5	−0.5
PCI66_3	−0.5	30% V_{CCO}	50% V_{CCO}	$V_{CCO} + 0.5$	10% V_{CCO}	90% V_{CCO}	1.5	−0.5
I2C	−0.5	25% V_{CCO}	70% V_{CCO}	4.1	20% V_{CCO}	—	3	—
SMBUS	−0.5	0.8	2.1	4.1	0.4	—	4	—
SDIO	−0.5	12.5% V_{CCO}	75% V_{CCO}	4.1	12.5% V_{CCO}	75% V_{CCO}	0.1	−0.1
MOBILE_DDR	−0.5	20% V_{CCO}	80% V_{CCO}	4.1	10% V_{CCO}	90% V_{CCO}	0.1	−0.1
HSTL_I	−0.5	$V_{REF} - 0.1$	$V_{REF} + 0.1$	4.1	0.4	$V_{CCO} - 0.4$	8	−8
HSTL_II	−0.5	$V_{REF} - 0.1$	$V_{REF} + 0.1$	4.1	0.4	$V_{CCO} - 0.4$	16	−16
HSTL_III	−0.5	$V_{REF} - 0.1$	$V_{REF} + 0.1$	4.1	0.4	$V_{CCO} - 0.4$	24	−8
HSTL_I_18	−0.5	$V_{REF} - 0.1$	$V_{REF} + 0.1$	4.1	0.4	$V_{CCO} - 0.4$	11	−11
HSTL_II_18	−0.5	$V_{REF} - 0.1$	$V_{REF} + 0.1$	4.1	0.4	$V_{CCO} - 0.4$	22	−22
HSTL_III_18	−0.5	$V_{REF} - 0.1$	$V_{REF} + 0.1$	4.1	0.4	$V_{CCO} - 0.4$	30	−11
SSTL3_I	−0.5	$V_{REF} - 0.2$	$V_{REF} + 0.2$	4.1	$V_{TT} - 0.6$	$V_{TT} + 0.6$	8	−8
SSTL3_II	−0.5	$V_{REF} - 0.2$	$V_{REF} + 0.2$	4.1	$V_{TT} - 0.8$	$V_{TT} + 0.8$	16	−16
SSTL2_I	−0.5	$V_{REF} - 0.15$	$V_{REF} + 0.15$	4.1	$V_{TT} - 0.61$	$V_{TT} + 0.61$	8.1	−8.1
SSTL2_II	−0.5	$V_{REF} - 0.15$	$V_{REF} + 0.15$	4.1	$V_{TT} - 0.81$	$V_{TT} + 0.81$	16.2	−16.2
SSTL18_I	−0.5	$V_{REF} - 0.125$	$V_{REF} + 0.125$	4.1	$V_{TT} - 0.47$	$V_{TT} + 0.47$	6.7	−6.7
SSTL18_II	−0.5	$V_{REF} - 0.125$	$V_{REF} + 0.125$	4.1	$V_{TT} - 0.60$	$V_{TT} + 0.60$	13.4	−13.4
SSTL15_II	−0.5	$V_{REF} - 0.1$	$V_{REF} + 0.1$	4.1	$V_{TT} - 0.4$	$V_{TT} + 0.4$	13.4	−13.4

Notes:

1. Tested according to relevant specifications.
2. Using drive strengths of 2, 4, 6, 8, 12, 16, or 24 mA.
3. Using drive strengths of 2, 4, 6, 8, 12, or 16 mA.
4. Using drive strengths of 2, 4, 6, 8, or 12 mA.
5. For more information, refer to [UG381](#): *Spartan-6 FPGA SelectIO Resources User Guide*.

Switching Characteristics

All values represented in this data sheet are based on these speed specifications: v1.20 for -3, -3N, and -2; and v1.08 for -1L. Switching characteristics are specified on a per-speed-grade basis and can be designated as Advance, Preliminary, or Production. Each designation is defined as follows:

Advance

These specifications are based on simulations only and are typically available soon after device design specifications are frozen. Although speed grades with this designation are considered relatively stable and conservative, some under-reporting might still occur.

Preliminary

These specifications are based on complete ES (engineering sample) silicon characterization. Devices and speed grades with this designation are intended to give a better indication of the expected performance of production silicon. The probability of under-reporting delays is greatly reduced as compared to Advance data.

Production

These specifications are released once enough production silicon of a particular device family member has been characterized to provide full correlation between specifications and devices over numerous production lots. There is no under-reporting of delays, and customers receive formal notification of any subsequent changes. Typically, the slowest speed grades transition to Production before faster speed grades.

All specifications are always representative of worst-case supply voltage and junction temperature conditions.

Since individual family members are produced at different times, the migration from one category to another depends completely on the status of the fabrication process for each device.

The -1L speed grade refers to the lower-power Spartan-6 devices. The -3N speed grade refers to the Spartan-6 devices that do not support MCB functionality.

[Table 26](#) correlates the current status of each Spartan-6 device on a per speed grade basis.

Testing of Switching Characteristics

All devices are 100% functionally tested. Internal timing parameters are derived from measuring internal test patterns. Listed below are representative values.

For more specific, more precise, and worst-case guaranteed data, use the values reported by the static timing analyzer and back-annotate to the simulation net list. Unless otherwise noted, values apply to all Spartan-6 devices.

Table 26: Spartan-6 Device Speed Grade Designations

Device	Speed Grade Designations		
	Advance	Preliminary	Production
XC6SLX4 ⁽¹⁾			-3, -2, -1L
XC6SLX9			-3, -3N, -2, -1L
XC6SLX16			-3, -3N, -2, -1L
XC6SLX25			-3, -3N, -2, -1L
XC6SLX25T			-3, -3N, -2
XC6SLX45			-3, -3N, -2, -1L
XC6SLX45T			-3, -3N, -2
XC6SLX75			-3, -3N, -2, -1L
XC6SLX75T			-3, -3N, -2
XC6SLX100			-3, -3N, -2, -1L
XC6SLX100T			-3, -3N, -2
XC6SLX150			-3, -3N, -2, -1L
XC6SLX150T			-3, -3N, -2
XA6SLX4			-3, -2
XA6SLX9			-3, -2
XA6SLX16			-3, -2
XA6SLX25			-3, -2
XA6SLX25T			-3, -2
XA6SLX45			-3, -2
XA6SLX45T			-3, -2
XA6SLX75			-3, -2
XA6SLX75T			-3, -2
XA6SLX100			-2
XQ6SLX75			-2, -1L
XQ6SLX75T			-3, -2
XQ6SLX150			-2, -1L
XQ6SLX150T			-3, -2

Notes:

1. The XC6SLX4 is not available in the -3N speed grade.

Production Silicon and ISE Software Status

In some cases, a particular family member (and speed grade) is released to production before a speed specification is released with the correct label (Advance, Preliminary, Production). Any labeling discrepancies are corrected in subsequent speed specification releases. [Table 27](#) lists the production released Spartan-6 family member, speed grade, and the minimum corresponding supported speed specification version and ISE® software revisions. The ISE software and speed specifications listed are the minimum releases required for production. All subsequent releases of software and speed specifications are valid.

Table 27: Spartan-6 Device Production Software and Speed Specification Release⁽¹⁾

Device	Speed Grade Designations ⁽²⁾			
	-3 ⁽³⁾	-3N	-2 ⁽⁴⁾	-1L
XC6SLX4	ISE 12.4 v1.15	N/A	ISE 12.3 v1.12 ⁽⁵⁾	ISE 13.2 v1.07
XC6SLX9	ISE 12.4 v1.15	ISE 13.1 Update v1.18 ⁽⁷⁾	ISE 12.3 v1.12 ⁽⁵⁾	ISE 13.2 v1.07
XC6SLX16	ISE 12.1 v1.08	ISE 13.1 Update v1.18 ⁽⁷⁾	ISE 11.5 v1.06	ISE 13.2 v1.07
XC6SLX25	ISE 12.2 v1.11 ⁽⁶⁾	ISE 13.1 Update v1.18 ⁽⁷⁾	ISE 12.2 v1.11 ⁽⁶⁾	ISE 13.2 v1.07
XC6SLX25T	ISE 12.2 v1.11 ⁽⁶⁾	ISE 13.1 Update v1.18 ⁽⁷⁾	ISE 12.2 v1.11 ⁽⁶⁾	N/A
XC6SLX45	ISE 12.1 v1.08	ISE 13.1 Update v1.18 ⁽⁷⁾	ISE 11.5 v1.07	ISE 13.1 v1.06
XC6SLX45T	ISE 12.1 v1.08	ISE 13.1 Update v1.18 ⁽⁷⁾	ISE 12.1 v1.08	N/A
XC6SLX75	ISE 12.2 v1.11 ⁽⁶⁾	ISE 13.1 Update v1.18 ⁽⁷⁾	ISE 12.2 v1.11 ⁽⁶⁾	ISE 13.2 v1.07
XC6SLX75T	ISE 12.2 v1.11 ⁽⁶⁾	ISE 13.1 Update v1.18 ⁽⁷⁾	ISE 12.2 v1.11 ⁽⁶⁾	N/A
XC6SLX100	ISE 12.2 v1.11 ⁽⁶⁾	ISE 13.1 Update v1.18 ⁽⁷⁾	ISE 12.2 v1.11 ⁽⁶⁾	ISE 13.1 v1.06
XC6SLX100T	ISE 12.2 v1.11 ⁽⁶⁾	ISE 13.1 Update v1.18 ⁽⁷⁾	ISE 12.2 v1.11 ⁽⁶⁾	N/A
XC6SLX150	ISE 12.2 v1.11 ⁽⁶⁾	ISE 13.1 Update v1.18 ⁽⁷⁾	ISE 12.2 v1.11 ⁽⁶⁾	ISE 13.1 v1.06
XC6SLX150T	ISE 12.2 v1.11 ⁽⁶⁾	ISE 13.1 Update v1.18 ⁽⁷⁾	ISE 12.2 v1.11 ⁽⁶⁾	N/A
XA6SLX4	ISE 13.2 v1.19	N/A	ISE 13.2 v1.19	N/A
XA6SLX9	ISE 13.2 v1.19	N/A	ISE 13.2 v1.19	N/A
XA6SLX16	ISE 13.2 v1.19	N/A	ISE 13.2 v1.19	N/A
XA6SLX25	ISE 13.2 v1.19	N/A	ISE 13.2 v1.19	N/A
XA6SLX25T	ISE 13.2 v1.19	N/A	ISE 13.2 v1.19	N/A
XA6SLX45	ISE 13.2 v1.19	N/A	ISE 13.2 v1.19	N/A
XA6SLX45T	ISE 13.2 v1.19	N/A	ISE 13.2 v1.19	N/A
XA6SLX75	ISE 13.2 v1.19	N/A	ISE 13.2 v1.19	N/A
XA6SLX75T	ISE 13.2 v1.19	N/A	ISE 13.2 v1.19	N/A
XA6SLX100	N/A	N/A	ISE 13.3 v1.20	N/A

Table 28: IOB Switching Characteristics for the Commercial (XC) Spartan-6 Devices (Cont'd)

I/O Standard	T _{IOPI}				T _{IOOP}				T _{IOTP}				Units
	Speed Grade				Speed Grade				Speed Grade				
	-3	-3N	-2	-1L ⁽¹⁾	-3	-3N	-2	-1L ⁽¹⁾	-3	-3N	-2	-1L ⁽¹⁾	
LVC MOS18, Slow, 24 mA	1.18	1.30	1.43	2.04	1.99	2.13	2.33	2.95	1.99	2.13	2.33	2.95	ns
LVC MOS18, Fast, 2 mA	1.18	1.30	1.43	2.04	3.59	3.73	3.93	4.53	3.59	3.73	3.93	4.53	ns
LVC MOS18, Fast, 4 mA	1.18	1.30	1.43	2.04	2.39	2.53	2.73	3.35	2.39	2.53	2.73	3.35	ns
LVC MOS18, Fast, 6 mA	1.18	1.30	1.43	2.04	1.88	2.02	2.22	2.84	1.88	2.02	2.22	2.84	ns
LVC MOS18, Fast, 8 mA	1.18	1.30	1.43	2.04	1.81	1.95	2.15	2.77	1.81	1.95	2.15	2.77	ns
LVC MOS18, Fast, 12 mA	1.18	1.30	1.43	2.04	1.71	1.85	2.05	2.67	1.71	1.85	2.05	2.67	ns
LVC MOS18, Fast, 16 mA	1.18	1.30	1.43	2.04	1.71	1.85	2.05	2.67	1.71	1.85	2.05	2.67	ns
LVC MOS18, Fast, 24 mA	1.18	1.30	1.43	2.04	1.71	1.85	2.05	2.67	1.71	1.85	2.05	2.67	ns
LVC MOS18_JEDEC, QUIETIO, 2 mA	0.94	1.06	1.19	1.41	5.91	6.05	6.25	6.79	5.91	6.05	6.25	6.79	ns
LVC MOS18_JEDEC, QUIETIO, 4 mA	0.94	1.06	1.19	1.41	4.75	4.89	5.09	5.64	4.75	4.89	5.09	5.64	ns
LVC MOS18_JEDEC, QUIETIO, 6 mA	0.94	1.06	1.19	1.41	4.04	4.18	4.38	4.96	4.04	4.18	4.38	4.96	ns
LVC MOS18_JEDEC, QUIETIO, 8 mA	0.94	1.06	1.19	1.41	3.71	3.85	4.05	4.62	3.71	3.85	4.05	4.62	ns
LVC MOS18_JEDEC, QUIETIO, 12 mA	0.94	1.06	1.19	1.41	3.35	3.49	3.69	4.28	3.35	3.49	3.69	4.28	ns
LVC MOS18_JEDEC, QUIETIO, 16 mA	0.94	1.06	1.19	1.41	3.20	3.34	3.54	4.13	3.20	3.34	3.54	4.13	ns
LVC MOS18_JEDEC, QUIETIO, 24 mA	0.94	1.06	1.19	1.41	2.96	3.10	3.30	3.98	2.96	3.10	3.30	3.98	ns
LVC MOS18_JEDEC, Slow, 2 mA	0.94	1.06	1.19	1.41	4.59	4.73	4.93	5.54	4.59	4.73	4.93	5.54	ns
LVC MOS18_JEDEC, Slow, 4 mA	0.94	1.06	1.19	1.41	3.69	3.83	4.03	4.60	3.69	3.83	4.03	4.60	ns
LVC MOS18_JEDEC, Slow, 6 mA	0.94	1.06	1.19	1.41	3.00	3.14	3.34	3.94	3.00	3.14	3.34	3.94	ns
LVC MOS18_JEDEC, Slow, 8 mA	0.94	1.06	1.19	1.41	2.19	2.33	2.53	3.18	2.19	2.33	2.53	3.18	ns
LVC MOS18_JEDEC, Slow, 12 mA	0.94	1.06	1.19	1.41	1.99	2.13	2.33	2.95	1.99	2.13	2.33	2.95	ns
LVC MOS18_JEDEC, Slow, 16 mA	0.94	1.06	1.19	1.41	1.99	2.13	2.33	2.95	1.99	2.13	2.33	2.95	ns
LVC MOS18_JEDEC, Slow, 24 mA	0.94	1.06	1.19	1.41	1.99	2.13	2.33	2.95	1.99	2.13	2.33	2.95	ns
LVC MOS18_JEDEC, Fast, 2 mA	0.94	1.06	1.19	1.41	3.57	3.71	3.91	4.52	3.57	3.71	3.91	4.52	ns
LVC MOS18_JEDEC, Fast, 4 mA	0.94	1.06	1.19	1.41	2.39	2.53	2.73	3.35	2.39	2.53	2.73	3.35	ns
LVC MOS18_JEDEC, Fast, 6 mA	0.94	1.06	1.19	1.41	1.88	2.02	2.22	2.84	1.88	2.02	2.22	2.84	ns
LVC MOS18_JEDEC, Fast, 8 mA	0.94	1.06	1.19	1.41	1.80	1.94	2.14	2.76	1.80	1.94	2.14	2.76	ns
LVC MOS18_JEDEC, Fast, 12 mA	0.94	1.06	1.19	1.41	1.72	1.86	2.06	2.68	1.72	1.86	2.06	2.68	ns
LVC MOS18_JEDEC, Fast, 16 mA	0.94	1.06	1.19	1.41	1.72	1.86	2.06	2.68	1.72	1.86	2.06	2.68	ns
LVC MOS18_JEDEC, Fast, 24 mA	0.94	1.06	1.19	1.41	1.72	1.86	2.06	2.68	1.72	1.86	2.06	2.68	ns
LVC MOS15, QUIETIO, 2 mA	0.98	1.10	1.23	1.79	5.47	5.61	5.81	6.38	5.47	5.61	5.81	6.38	ns
LVC MOS15, QUIETIO, 4 mA	0.98	1.10	1.23	1.79	4.61	4.75	4.95	5.51	4.61	4.75	4.95	5.51	ns
LVC MOS15, QUIETIO, 6 mA	0.98	1.10	1.23	1.79	4.07	4.21	4.41	4.97	4.07	4.21	4.41	4.97	ns
LVC MOS15, QUIETIO, 8 mA	0.98	1.10	1.23	1.79	3.91	4.05	4.25	4.81	3.91	4.05	4.25	4.81	ns
LVC MOS15, QUIETIO, 12 mA	0.98	1.10	1.23	1.79	3.53	3.67	3.87	4.51	3.53	3.67	3.87	4.51	ns
LVC MOS15, QUIETIO, 16 mA	0.98	1.10	1.23	1.79	3.32	3.46	3.66	4.31	3.32	3.46	3.66	4.31	ns
LVC MOS15, Slow, 2 mA	0.98	1.10	1.23	1.79	4.18	4.32	4.52	5.11	4.18	4.32	4.52	5.11	ns
LVC MOS15, Slow, 4 mA	0.98	1.10	1.23	1.79	3.42	3.56	3.76	4.34	3.42	3.56	3.76	4.34	ns
LVC MOS15, Slow, 6 mA	0.98	1.10	1.23	1.79	2.29	2.43	2.63	3.24	2.29	2.43	2.63	3.24	ns

Table 34: SSO Limit per V_{CCO}/GND Pair

V_{CCO}	I/O Standard	Drive	Slew	SSO Limit per V_{CCO}/GND Pair			
				All TQG144, CPG196, CSG225, FT(G)256, and LX devices in CSG324		All CS(G)484, FG(G)484, FG(G)676, FG(G)900, and LXT devices in CSG324	
				Bank 0/2	Bank 1/3	Bank 0/2	Bank 1/3/4/5
1.2V	LVCMOS12, LVCMOS12_JEDEC	2	Fast	30 ⁽¹⁾	35	30	35
			Slow	51	55	51	52
			QuietIO	71	58	71	70
		4	Fast	17	17	17	19
			Slow	23	25	23	22
			QuietIO	35	32	35	32
		6	Fast	13	15	13	14
			Slow	19	20	19	17
			QuietIO	26	24	26	24
		8	Fast	N/A	12	N/A	12
			Slow	N/A	15	N/A	13
			QuietIO	N/A	20	N/A	19
		12	Fast	N/A	5	N/A	4
			Slow	N/A	8	N/A	5
			QuietIO	N/A	11	N/A	10

Table 34: SSO Limit per V_{CCO}/GND Pair (Cont'd)

V _{CCO}	I/O Standard	Drive	Slew	SSO Limit per V _{CCO} /GND Pair				
				All TQG144, CPG196, CSG225, FT(G)256, and LX devices in CSG324		All CS(G)484, FG(G)484, FG(G)676, FG(G)900, and LXT devices in CSG324		
				Bank 0/2	Bank 1/3	Bank 0/2	Bank 1/3/4/5	
1.8V	LVCMOS18, LVCMOS18_JEDEC	2	Fast	39	46	39	47	
			Slow	65	75	65	74	
			QuietIO	80	80	80	85	
		4	Fast	22	25	22	25	
			Slow	38	36	38	29	
			QuietIO	45	40	45	35	
		6	Fast	16	18	16	17	
			Slow	27	25	27	19	
			QuietIO	30	28	30	23	
		8	Fast	13	15	13	14	
			Slow	16	18	16	16	
			QuietIO	25	22	25	18	
		12	Fast	5	7	5	5	
			Slow	7	8	7	6	
			QuietIO	11	10	11	8	
		16	Fast	4	5	4	4	
			Slow	7	8	7	5	
			QuietIO	11	10	11	8	
		24	Fast	N/A	5	N/A	3	
			Slow	N/A	8	N/A	8	
			QuietIO	N/A	10	N/A	8	
	HSTL_I_18				9	10	9	9
	HSTL_II_18				N/A	5	N/A	6
	HSTL_III_18				9	10	9	11
	DIFF_HSTL_I_18				27	30	27	27
	DIFF_HSTL_II_18				N/A	15	N/A	18
	DIFF_HSTL_III_18				27	30	27	33
	MOBILE_DDR ⁽³⁾				12	14	12	14
	DIFF_MOBILE_DDR ⁽³⁾				36	42	36	42
	SSTL_18_I ⁽³⁾				9	10	9	10
	SSTL_18_II ⁽³⁾				N/A	5	N/A	4
	DIFF_SSTL_18_I ⁽³⁾				27	30	27	30
	DIFF_SSTL_18_II ⁽³⁾				N/A	15	N/A	12

Table 34: SSO Limit per V_{CCO}/GND Pair (Cont'd)

V _{CCO}	I/O Standard	Drive	Slew	SSO Limit per V _{CCO} /GND Pair				
				All TQG144, CPG196, CSG225, FT(G)256, and LX devices in CSG324		All CS(G)484, FG(G)484, FG(G)676, FG(G)900, and LXT devices in CSG324		
				Bank 0/2	Bank 1/3	Bank 0/2	Bank 1/3/4/5	
2.5V	LVCMOS25	2	Fast	38	43	38	43	
			Slow	46	52	46	48	
			QuietIO	57	64	57	59	
		4	Fast	21	24	21	23	
			Slow	26	31	26	27	
			QuietIO	33	32	33	30	
		6	Fast	15	17	15	16	
			Slow	19	22	19	19	
			QuietIO	25	23	25	19	
		8	Fast	12	15	12	14	
			Slow	15	18	15	16	
			QuietIO	21	19	21	16	
		12	Fast	1	3	1	1	
			Slow	2	7	2	4	
			QuietIO	3	8	3	8	
		16	Fast	1	3	1	1	
			Slow	3	7	3	3	
			QuietIO	4	9	4	8	
		24	Fast	N/A	3	N/A	1	
			Slow	N/A	5	N/A	2	
			QuietIO	N/A	8	N/A	6	
	SSTL_2_I ⁽³⁾				10	11	10	11
	SSTL_2_II ⁽³⁾				N/A	7	N/A	7
	DIFF_SSTL_2_I ⁽³⁾				30	33	30	33
	DIFF_SSTL_2_II ⁽³⁾				N/A	21	N/A	24

Table 34: SSO Limit per V_{CCO}/GND Pair (Cont'd)

V_{CCO}	I/O Standard	Drive	Slew	SSO Limit per V_{CCO}/GND Pair			
				All TQG144, CPG196, CSG225, FT(G)256, and LX devices in CSG324		All CS(G)484, FG(G)484, FG(G)676, FG(G)900, and LXT devices in CSG324	
				Bank 0/2	Bank 1/3	Bank 0/2	Bank 1/3/4/5
Various	LVDS_33			16	N/A	16	N/A
	LVDS_25			20	N/A	20	N/A
	BLVDS_25			20	48	20	20
	MINI_LVDS_33			13	N/A	13	N/A
	MINI_LVDS_25			18	N/A	18	N/A
	RSDS_33			12	N/A	12	N/A
	RSDS_25			15	N/A	15	N/A
	TMDS_33			83	N/A	83	N/A
	PPDS_33			12	N/A	12	N/A
	PPDS_25			16	N/A	16	N/A
	DISPLAY_PORT			42	40	42	30
	I2C			47	55	47	42
	SMBUS			44	52	44	40

Notes:

- SSO limits greater than the number of I/O per V_{CCO}/GND pair (Table 33) indicate No Limit for the given I/O standard. They are provided in this table to calculate limits when using multiple I/O standards in a bank.
- Not available (N/A) indicates that the I/O standard is not available in the given bank.
- When used with the MCB, these signals are exempt from SSO analysis due to the known activity of the MCB switching patterns. SSO performance is validated for all MCB instances. MCB outputs can, in some cases, exceed the SSO limits.

DSP48A1 Switching Characteristics

Table 44: DSP48A1 Switching Characteristics

Symbol	Description	Pre-adder	Multiplier	Post-adder	Speed Grade				Units
					-3	-3N	-2	-1L	
Setup and Hold Times of Data/Control Pins to the Input Register Clock									
T _{DSPDCK_A_A1REG} / T _{DSPCKD_A_A1REG}	A input to A1 register CLK	N/A	N/A	N/A	0.15/ 0.09	0.17/ 0.09	0.17/ 0.09	0.32/ 0.09	ns
T _{DSPDCK_D_B1REG} / T _{DSPCKD_D_B1REG}	D input to B1 register CLK	Yes	N/A	N/A	1.90/ −0.07	1.95/ −0.07	1.95/ −0.07	2.82/ −0.07	ns
T _{DSPDCK_C_CREG} / T _{DSPCKD_C_CREG}	C input to C register CLK for XC devices	N/A	N/A	N/A	0.11/ 0.15	0.13/ 0.15	0.13/ 0.15	0.24/ 0.09	ns
	C input to C register CLK for XA and XQ devices				0.11/ 0.19	N/A	0.13/ 0.23	0.24/ 0.09	
T _{DSPDCK_D_DREG} / T _{DSPCKD_D_DREG}	D input to D register CLK for XC devices	N/A	N/A	N/A	0.09/ 0.15	0.10/ 0.15	0.10/ 0.15	0.19/ 0.12	ns
	D input to D register CLK for XA and XQ devices				0.09/ 0.23	N/A	0.10/ 0.27	0.19/ 0.12	
T _{DSPDCK_OPMODE_B1REG} / T _{DSPCKD_OPMODE_B1REG}	OPMODE input to B1 register CLK	Yes	N/A	N/A	1.97/ 0.01	2.00/ 0.01	2.00/ 0.01	2.85/ 0.01	ns
T _{DSPDCK_OPMODE_OPMODEREG} / T _{DSPCKD_OPMODE_OPMODEREG}	OPMODE input to OPMODE register CLK for XC devices	N/A	N/A	N/A	0.18/ 0.12	0.21/ 0.12	0.21/ 0.12	0.40/ 0.12	ns
	OPMODE input to OPMODE register CLK for XA and XQ devices				0.18/ 0.16	N/A	0.21/ 0.22	0.40/ 0.12	
Setup and Hold Times of Data Pins to the Pipeline Register Clock									
T _{DSPDCK_A_MREG} / T _{DSPCKD_A_MREG}	A input to M register CLK	N/A	Yes	N/A	3.06/ −0.40	3.51/ −0.40	3.51/ −0.40	3.97/ −0.40	ns
T _{DSPDCK_B_MREG} / T _{DSPCKD_B_MREG}	B input to M register CLK	Yes	Yes	N/A	3.96/ −0.68	4.58/ −0.68	4.58/ −0.68	7.00/ −0.68	ns
T _{DSPDCK_D_MREG} / T _{DSPCKD_D_MREG}	D input to M register CLK	Yes	Yes	N/A	4.23/ −0.56	4.80/ −0.56	4.80/ −0.56	6.84/ −0.56	ns
T _{DSPDCK_OPMODE_MREG} / T _{DSPCKD_OPMODE_MREG}	OPMODE to M register CLK	Yes	Yes	N/A	4.18/ −0.48	4.80/ −0.48	4.80/ −0.48	6.88/ −0.48	ns
		No	Yes	N/A	2.37/ −0.48	2.70/ −0.48	2.70/ −0.48	4.28/ −0.48	ns
Setup and Hold Times of Data/Control Pins to the Output Register Clock									
T _{DSPDCK_A_PREG} / T _{DSPCKD_A_PREG}	A input to P register CLK	N/A	Yes	Yes	4.32/ −0.76	5.06/ −0.76	5.06/ −0.76	7.52/ −0.76	ns
T _{DSPDCK_B_PREG} / T _{DSPCKD_B_PREG}	B input to P register CLK	Yes	Yes	Yes	5.87/ −0.59	6.87/ −0.59	6.87/ −0.59	10.55/ −0.59	ns
		No	Yes	Yes	4.14/ −0.93	4.68/ −0.93	4.68/ −0.93	8.12/ −0.93	ns
T _{DSPDCK_C_PREG} / T _{DSPCKD_C_PREG}	C input to P register CLK	N/A	N/A	Yes	2.20/ −0.23	2.25/ −0.23	2.25/ −0.23	3.27/ −0.23	ns
T _{DSPDCK_D_PREG} / T _{DSPCKD_D_PREG}	D input to P register CLK	Yes	Yes	Yes	5.90/ −0.92	6.91/ −0.92	6.91/ −0.92	10.39/ −0.92	ns

Table 44: DSP48A1 Switching Characteristics (Cont'd)

Symbol	Description	Pre-adder	Multiplier	Post-adder	Speed Grade				Units
					-3	-3N	-2	-1L	
T _{DSPDCK_OPMODE_PREG} / T _{DSPCKD_OPMODE_PREG}	OPMODE input to P register CLK	Yes	Yes	Yes	6.21/ −0.84	7.27/ −0.84	7.27/ −0.84	10.43/ −0.84	ns
		No	Yes	Yes	1.69/ −0.87	1.98/ −0.87	1.98/ −0.87	3.62/ −0.87	ns
		No	No	Yes	2.09/ −0.22	2.30/ −0.22	2.30/ −0.22	3.79/ −0.22	ns
Clock to Out from Output Register Clock to Output Pin									
T _{DSPCKO_P_PREG}	CLK (PREG) to P output	N/A	N/A	N/A	1.20	1.34	1.34	1.90	ns
Clock to Out from Pipeline Register Clock to Output Pins									
T _{DSPCKO_P_MREG}	CLK (MREG) to P output	N/A	N/A	Yes	3.38	3.95	3.95	5.83	ns
Clock to Out from Input Register Clock to Output Pins									
T _{DSPCKO_P_A1REG}	CLK (A1REG) to P output	N/A	Yes	Yes	5.02	5.87	5.87	9.65	ns
T _{DSPCKO_P_B1REG}	CLK (B1REG) to P output	N/A	Yes	Yes	5.02	5.87	5.87	9.63	ns
T _{DSPCKO_P_CREG}	CLK (CREG) to P output	N/A	N/A	Yes	3.12	3.64	3.64	5.24	ns
T _{DSPCKO_P_DREG}	CLK (DREG) to P output	Yes	Yes	Yes	6.77	7.92	7.92	12.53	ns
Combinatorial Delays from Input Pins to Output Pins									
T _{DSPDO_A_P}	A input to P output	N/A	No	Yes	2.85	3.33	3.33	4.73	ns
		N/A	Yes	No ⁽²⁾	3.35	3.93	3.93	6.74	ns
		N/A	Yes	Yes	4.56	5.22	5.22	8.94	ns
T _{DSPDO_B_P}	B input to P output	Yes	No	No ⁽²⁾	3.22	3.76	3.76	5.55	ns
		Yes	Yes	No ⁽²⁾	6.01	6.54	6.54	9.76	ns
		Yes	Yes	Yes	6.27	7.34	7.34	11.96	ns
T _{DSPDO_C_P}	C input to P output	N/A	N/A	Yes	2.69	3.15	3.15	4.68	ns
T _{DSPDO_D_P}	D input to P output	Yes	Yes	Yes	6.31	7.38	7.38	11.81	ns
T _{DSPDO_OPMODE_P}	OPMODE input to P output	Yes	Yes	Yes	6.43	7.52	7.52	11.84	ns
		No	Yes	Yes	4.84	5.66	5.66	9.25	ns
		No	No	Yes	3.11	3.49	3.49	5.03	ns
Maximum Frequency									
F _{MAX}	All registers used	Yes	Yes	Yes	390	333	333	213	MHz

Notes:

1. A Yes signifies that the component is in the path. A No signifies that the component is being bypassed. N/A signifies not applicable because no path exists.
2. Implemented in the post-adder by adding to zero.

Configuration Switching Characteristics

Table 47: Configuration Switching Characteristics⁽¹⁾

Symbol	Description	Speed Grade				Units
		-3	-3N	-2	-1L	
Power-up Timing Characteristics						
T _{PL} ⁽²⁾	PROGRAM_B Latency	4	4	4	5	ms, Max
T _{POR} ⁽²⁾	Power-on reset (50 ms ramp time) ⁽³⁾	5/30	5/34	5/40	5/40	ms, Min/Max
	Power-on reset (10 ms ramp time)	5/25	5/29	5/35	5/40	ms, Min/Max
T _{PROGRAM}	PROGRAM_B Pulse Width	500	500	500	500	ns, Min
Slave Serial Mode Programming Switching						
T _{DCCK} /T _{CCKD}	DIN Setup/Hold, slave mode	6.0/1.0	6.0/1.0	6.0/1.0	8.0/2.0	ns, Min
T _{CCO}	CCLK to DOUT	12	12	12	17	ns, Max
F _{SCCK}	Slave mode external CCLK	80	80	80	50	MHz, Max
Slave SelectMAP Mode Programming Switching						
T _{SMDCK} /T _{SMCKD}	SelectMAP Data Setup/Hold	6.0/1.0	6.0/1.0	6.0/1.0	8.0/2.0	ns, Min
T _{SMCSCCK} /T _{SMCKCS}	CSI_B Setup/Hold	7.0/0.0	7.0/0.0	7.0/0.0	9.0/2.0	ns, Min
T _{SMWCCK} /T _{SMCKW}	RDWR_B Setup/Hold	17.0/1.0	17.0/1.0	17.0/1.0	27.0/2.0	ns, Min
T _{SMCKCSO}	CSO_B clock to out	16	16	16	26	ns, Max
T _{SMCO}	CCLK to DATA out in readback	13	13	13	25	ns, Max
T _{SMCKBY}	CCLK to BUSY out in readback	12	12	12	17	ns, Max
F _{SMCK}	Maximum CCLK frequency (LX4, LX9, LX16, LX25, LX25T, LX45, LX45T, LX75, and LX75T only)	50	50	50	25	MHz, Max
	Maximum CCLK frequency (LX100 and LX100T in x8 mode, LX150, and LX150T only)	40	40	40	20	MHz, Max
	Maximum CCLK frequency (LX100 and LX100T in x16 mode only)	35	35	35	20	MHz, Max
F _{RBCK}	Maximum Readback CCLK frequency, including block RAM (LX4, LX9, LX16, LX25, LX25T, LX45, LX45T, LX75, and LX75T only)	20	20	20	4	MHz, Max
	Maximum Readback CCLK frequency, ignoring block RAM (POST_CRC) (LX4, LX9, LX16, LX25, LX25T, LX45, LX45T, LX75, and LX75T only)	50	50	50	30	MHz, Max
	Maximum Readback CCLK frequency, including block RAM (LX100, LX100T, LX150, and LX150T only)	12	12	12	4	MHz, Max
	Maximum Readback CCLK frequency, ignoring block RAM (POST_CRC) (LX100, LX100T, LX150, and LX150T only)	35	35	35	20	MHz, Max
Boundary-Scan Port Timing Specifications						
T _{TAPTCK}	TMS and TDI Setup time before TCK	10	10	10	17	ns, Min
T _{TCKTAP}	TMS and TDI Hold time after TCK	5.5	5.5	5.5	5.5	ns, Min
T _{TCKTDO}	TCK falling edge to TDO output valid	6.5	6.5	6.5	8	ns, Max
T _{TCKH}	TCK clock minimum High time	12	12	12	21	ns, Min
T _{TCKL}	TCK clock minimum Low time	12	12	12	21	ns, Min
F _{TCK}	Maximum configuration TCK clock frequency	33	33	33	18	MHz, Max
F _{TCKB}	Maximum boundary-scan TCK clock frequency	33	33	33	18	MHz, Max
F _{TCKAES}	Maximum AES key TCK clock frequency	2	2	2	2	MHz, Max

Table 47: Configuration Switching Characteristics⁽¹⁾ (Cont'd)

Symbol	Description	Speed Grade				Units
		-3	-3N	-2	-1L	
BPI Master Flash Mode Programming Switching ⁽⁴⁾						
T _{BPICCO} ⁽⁵⁾	A[25:0], FCS_B, FOE_B, FWE_B, LDC outputs valid after CCLK falling edge	15	15	15	20	ns, Max
T _{BPIICCK}	Master BPI CCLK (output) delay	10/100	10/100	10/100	10/130	μs, Min/Max
T _{BPIDCC} /T _{BPICCD}	Setup/Hold on D[15:0] data input pins	5.0/1.0	5.0/1.0	5.0/1.0	6.0/2.0	ns, Min
SPI Master Flash Mode Programming Switching ⁽⁶⁾						
T _{SPIDCC} /T _{SPIDCCD}	DIN, MISO0, MISO1, MISO2, MISO3, Setup/Hold before/after the rising CCLK edge	5.0/1.0	5.0/1.0	5.0/1.0	7.0/1.0	ns, Min
T _{SPIICCK}	Master SPI CCLK (output) delay	0.4/7.0	0.4/7.0	0.4/7.0	0.4/10.0	μs, Min/Max
T _{SPICCM}	MOSI clock to out	13	13	13	19	ns, Max
T _{SPICCFC}	CSO_B clock to out	16	16	16	26	ns, Max
CCLK Output (Master Modes)						
T _{MCCKL}	Master CCLK clock duty cycle Low	40/60				%, Min/Max
T _{MCCKH}	Master CCLK clock duty cycle High	40/60				%, Min/Max
F _{MCCK}	Maximum frequency, serial mode (Master Serial/SPI) All devices	40	40	40	30	MHz, Max
	Maximum frequency, parallel mode (Master SelectMAP/BPI) LX9, LX16, LX25, LX25T, LX45, LX45T, LX75, and LX75T	40	40	40	25	MHz, Max
	Maximum frequency, parallel mode (Master SelectMAP/BPI) LX100 and LX100T in x8 mode, LX150, and LX150T	40	40	40	20	MHz, Max
	Maximum frequency, parallel mode (Master SelectMAP/BPI) LX100 and LX100T in x16 mode	35	35	35	20	MHz, Max
F _{MCCKTOL}	Frequency Tolerance, master mode	±50	±50	±50	±50	%
CCLK Input (Slave Modes)						
T _{SCCKL}	Slave CCLK clock minimum Low time	5	5	5	8	ns, Min
T _{SCCKH}	Slave CCLK clock minimum High time	5	5	5	8	ns, Min
USERCCLK Input						
T _{USERCCLKL}	USERCCLK clock minimum Low time	12	12	12	16	ns, Min
T _{USERCCLKH}	USERCCLK clock minimum High time	12	12	12	16	ns, Min
F _{USERCCLK}	Maximum USERCCLK frequency	40	40	40	30	MHz, Max

Notes:

- Maximum frequency and setup/hold timing parameters are for 3.3V and 2.5V configuration voltages.
- To support longer delays in configuration, use the design solutions described in [UG380: Spartan-6 FPGA Configuration User Guide](#).
- [Table 6](#) specifies the power supply ramp time.
- BPI mode is not supported in:
 - LX4, LX25, or LX25T devices
 - LX9 devices in the TQG144 package
 - LX9 or LX16 devices in the CPG196 package.
- Only during configuration, the last edge is determined by a weak pull-up/pull-down resistor in the I/O.
- Defense-grade Spartan-6Q -2Q devices configure in single default SPI Master (x1) mode at $T_j = -55^{\circ}\text{C}$. During operation and when using all other configuration functions, the minimum operating temperature is -40°C .

Table 57: Switching Characteristics for the Digital Frequency Synthesizer DFS (DCM_CLKGEN)⁽¹⁾

Symbol	Description	Speed Grade								Units
		-3		-3N		-2		-1L		
		Min	Max	Min	Max	Min	Max	Min	Max	
Output Frequency Ranges (DCM_CLKGEN)										
CLKOUT_FREQ_FX	Frequency for the CLKFX and CLKFX180 outputs	5	375	5	375	5	333	5	200	MHz
CLKOUT_FREQ_FXDV	Frequency for the CLKFXDV output	0.15625	187.5	0.15625	187.5	0.15625	166.5	0.15625	100	MHz
Output Clock Jitter ⁽²⁾⁽³⁾										
CLKOUT_PER_JITT_FX	Period jitter at the CLKFX and CLKFX180 outputs.	Typical = ±[0.2% of CLKFX period + 100]								ps
CLKOUT_PER_JITT_FXDV	Period jitter at the CLKFXDV output.	Typical = ±[0.2% of CLKFX period + 100]								ps
CLKFX_FREEZE_VAR	CLKFX period change in free running oscillator mode at the same temperature. FCLKFX > 50 MHz	Maximum = ±3% of CLKFX period								ps
	CLKFX period change in free running oscillator mode at the same temperature. FCLKFX < 50 MHz	Maximum = ±5% of CLKFX period								ps
CLKFX_FREEZE_TEMP_SLOPE	CLKFX period will change in free_oscillator mode over temperature. Add to CLKFX_FREEZE_VAR to determine total CLKFX period change. Percentage change for CLKFX period over 1°C.	Maximum = 0.1								%/°C
Duty Cycle ⁽⁴⁾⁽⁵⁾										
CLKOUT_DUTY_CYCLE_FX	Duty cycle precision for the CLKFX and CLKFX180 outputs, including the BUFGMUX and clock tree duty-cycle distortion	Maximum = ±[1% of CLKFX period + 350]								ps
CLKOUT_DUTY_CYCLE_FXDV	Duty cycle precision for the CLKFXDV outputs, including the BUFGMUX and clock tree duty-cycle distortion	Maximum = ±[1% of CLKFX period + 350]								ps
Lock Time										
LOCK_FX ⁽²⁾	The time from deassertion at the DCM's Reset input to the rising transition at its LOCKED output. The DFS asserts LOCKED when the CLKFX, CLKFX180, and CLKFXDV signals are valid. Lock time requires CLKFX_DIVIDE < F _{IN} /(0.50 MHz) when: F _{CLKIN} < 50 MHz	—	50	—	50	—	50	—	50	ms
	when: F _{CLKIN} > 50 MHz	—	5	—	5	—	5	—	5	ms

Table 65: Global Clock Input to Output Delay With DCM in Source-Synchronous Mode

Symbol	Description	Device	Speed Grade				Units
			-3	-3N	-2	-1L	
LVCMOS25 Global Clock Input to Output Delay using Output Flip-Flop, 12mA, Fast Slew Rate, <i>with</i> DCM in Source-Synchronous Mode.							
T _{ICKOFDCM_0}	Global Clock and OUTFF <i>with</i> DCM	XC6SLX4	5.03	N/A	7.21	8.05	ns
		XC6SLX9	5.03	6.13	7.21	8.05	ns
		XC6SLX16	5.08	5.51	6.44	7.96	ns
		XC6SLX25	4.81	5.13	5.69	7.94	ns
		XC6SLX25T	4.81	5.13	5.69	N/A	ns
		XC6SLX45	5.26	5.69	6.63	7.92	ns
		XC6SLX45T	5.26	5.69	6.63	N/A	ns
		XC6SLX75	4.77	5.18	5.88	7.95	ns
		XC6SLX75T	4.77	5.18	5.88	N/A	ns
		XC6SLX100	4.72	5.11	5.76	8.59	ns
		XC6SLX100T	4.76	5.11	5.76	N/A	ns
		XC6SLX150	4.90	5.30	5.93	7.93	ns
		XC6SLX150T	4.90	5.30	5.93	N/A	ns
		XA6SLX4	5.35	N/A	7.21	N/A	ns
		XA6SLX9	5.35	N/A	7.21	N/A	ns
		XA6SLX16	5.42	N/A	6.44	N/A	ns
		XA6SLX25	5.13	N/A	5.69	N/A	ns
		XA6SLX25T	5.13	N/A	5.79	N/A	ns
		XA6SLX45	5.58	N/A	6.63	N/A	ns
		XA6SLX45T	5.58	N/A	6.63	N/A	ns
		XA6SLX75	5.09	N/A	5.87	N/A	ns
		XA6SLX75T	5.09	N/A	5.87	N/A	ns
		XA6SLX100	N/A	N/A	6.44	N/A	ns
		XQ6SLX75	N/A	N/A	5.87	7.95	ns
		XQ6SLX75T	5.09	N/A	5.87	N/A	ns
		XQ6SLX150	N/A	N/A	6.06	7.93	ns
		XQ6SLX150T	5.50	N/A	6.06	N/A	ns

Notes:

1. Listed above are representative values where one global clock input drives one vertical clock line in each accessible column, and where all accessible IOB and CLB flip-flops are clocked by the global clock net.
2. DCM output jitter is already included in the timing calculation.

Table 73: Global Clock Setup and Hold With DCM in Source-Synchronous Mode

Symbol	Description	Device	Speed Grade				Units
			-3	-3N	-2	-1L	
Input Setup and Hold Time Relative to Global Clock Input Signal for LVC MOS25 Standard.(1)							
T _{PSDCM0} / T _{PHDCM0}	No Delay Global Clock and IFF(2) with DCM in Source-Synchronous Mode	XC6SLX4	0.71/0.65	N/A	0.72/1.22	1.58/1.18	ns
		XC6SLX9	0.71/0.69	0.71/1.19	0.72/1.36	1.58/1.18	ns
		XC6SLX16	0.86/0.52	0.92/0.57	1.04/0.60	1.02/1.06	ns
		XC6SLX25	0.84/0.58	0.90/0.59	1.01/0.59	1.58/1.07	ns
		XC6SLX25T	0.84/0.58	0.90/0.59	1.01/0.59	N/A	ns
		XC6SLX45	0.85/0.70	0.90/0.76	0.98/0.79	1.34/1.34	ns
		XC6SLX45T	0.85/0.70	0.90/0.76	0.98/0.79	N/A	ns
		XC6SLX75	1.00/0.62	1.06/0.63	1.15/0.63	1.65/1.46	ns
		XC6SLX75T	1.00/0.71	1.06/0.72	1.15/0.72	N/A	ns
		XC6SLX100	0.81/0.68	0.81/0.69	0.94/0.69	1.42/2.07	ns
		XC6SLX100T	0.81/0.68	0.81/0.69	0.94/0.69	N/A	ns
		XC6SLX150	0.68/0.98	0.69/0.99	0.79/0.99	1.45/1.60	ns
		XC6SLX150T	0.68/0.98	0.69/0.99	0.79/0.99	N/A	ns
		XA6SLX4	0.81/0.74	N/A	0.72/1.36	N/A	ns
		XA6SLX9	0.81/0.74	N/A	0.72/1.36	N/A	ns
		XA6SLX16	1.01/0.56	N/A	1.04/0.60	N/A	ns
		XA6SLX25	0.94/0.76	N/A	1.06/0.77	N/A	ns
		XA6SLX25T	0.94/0.76	N/A	1.14/0.77	N/A	ns
		XA6SLX45	0.86/0.74	N/A	0.98/0.78	N/A	ns
		XA6SLX45T	0.86/0.74	N/A	0.98/0.78	N/A	ns
		XA6SLX75	1.02/0.71	N/A	1.15/0.72	N/A	ns
		XA6SLX75T	1.02/0.71	N/A	1.15/0.72	N/A	ns
		XA6SLX100	N/A	N/A	1.37/0.75	N/A	ns
		XQ6SLX75	N/A	N/A	1.15/0.72	1.65/1.46	ns
		XQ6SLX75T	1.02/0.71	N/A	1.15/0.72	N/A	ns
		XQ6SLX150	N/A	N/A	0.79/1.15	1.45/1.60	ns
		XQ6SLX150T	0.73/1.15	N/A	0.79/1.15	N/A	ns

Notes:

1. Setup and Hold times are measured over worst case conditions (process, voltage, temperature). Setup time is measured relative to the Global Clock input signal using the slowest process, highest temperature, and lowest voltage. Hold time is measured relative to the Global Clock input signal using the fastest process, lowest temperature, and highest voltage. These measurements include DCM CLK0 jitter.
2. IFF = Input Flip-Flop or Latch
3. Use IBIS to determine any duty-cycle distortion incurred using various standards.

Table 81: Source-Synchronous Pin-to-Pin Setup/Hold and Clock-to-Out Using BUFIO2

Symbol	Description	Device	Speed Grade				Units
			-3	-3N	-2	-1L	
Data Input Setup and Hold Times Relative to a Forwarded Clock Input Pin Using BUFIO2							
T _{PSCS} /T _{PHCS}	IFF setup/hold using BUFIO2 clock	XC6SLX4	0.57/0.94	N/A	0.95/1.12	0.27/1.56	ns
		XC6SLX9	0.40/0.95	0.50/0.96	0.60/1.12	0.27/1.56	ns
		XC6SLX16	0.48/0.74	0.55/0.75	0.69/0.83	1.27/1.31	ns
		XC6SLX25	0.28/1.02	0.28/1.12	0.28/1.24	0.15/1.78	ns
		XC6SLX25T	0.28/1.02	0.28/1.12	0.28/1.24	N/A	ns
		XC6SLX45	0.42/1.19	0.44/1.29	0.50/1.40	0.12/1.83	ns
		XC6SLX45T	0.42/1.19	0.44/1.29	0.50/1.40	N/A	ns
		XC6SLX75	0.38/1.48	0.38/1.63	0.38/1.84	0.05/2.78	ns
		XC6SLX75T	0.38/1.48	0.38/1.63	0.38/1.84	N/A	ns
		XC6SLX100	0.06/1.48	0.06/1.63	0.06/1.87	−0.03/2.72	ns
		XC6SLX100T	0.06/1.48	0.06/1.63	0.06/1.87	N/A	ns
		XC6SLX150	0.04/1.73	0.04/1.75	0.04/1.98	−0.08/3.07	ns
		XC6SLX150T	0.04/1.73	0.04/1.75	0.04/1.98	N/A	ns
		XA6SLX4	0.64/0.96	N/A	0.97/1.12	N/A	ns
		XA6SLX9	0.44/0.99	N/A	0.62/1.16	N/A	ns
		XA6SLX16	0.50/0.78	N/A	0.69/0.83	N/A	ns
		XA6SLX25	0.28/1.04	N/A	0.28/1.25	N/A	ns
		XA6SLX25T	0.28/1.04	N/A	0.28/1.25	N/A	ns
		XA6SLX45	0.43/1.21	N/A	0.50/1.40	N/A	ns
		XA6SLX45T	0.43/1.21	N/A	0.50/1.40	N/A	ns
		XA6SLX75	0.38/1.49	N/A	0.38/1.84	N/A	ns
		XA6SLX75T	0.38/1.49	N/A	0.38/1.84	N/A	ns
		XA6SLX100	N/A	N/A	1.01/1.63	N/A	ns
		XQ6SLX75	N/A	N/A	0.38/1.84	0.05/2.78	ns
		XQ6SLX75T	0.38/1.49	N/A	0.38/1.84	N/A	ns
		XQ6SLX150	N/A	N/A	0.04/1.98	−0.08/3.07	ns
		XQ6SLX150T	0.04/1.75	N/A	0.04/1.98	N/A	ns

Table 81: Source-Synchronous Pin-to-Pin Setup/Hold and Clock-to-Out Using BUFIO2 (Cont'd)

Symbol	Description	Device	Speed Grade				Units
			-3	-3N	-2	-1L	
Pin-to-Pin Clock-to-Out Using BUFIO2							
T _{ICKO} FCS	OFF clock-to-out using BUFIO2 clock	XC6SLX4	5.51	N/A	6.95	8.45	ns
		XC6SLX9	5.51	5.89	6.95	8.45	ns
		XC6SLX16	5.31	5.70	6.67	8.21	ns
		XC6SLX25	5.53	6.00	7.02	8.72	ns
		XC6SLX25T	5.53	6.00	7.02	N/A	ns
		XC6SLX45	5.76	6.18	7.22	8.77	ns
		XC6SLX45T	5.76	6.18	7.22	N/A	ns
		XC6SLX75	5.94	6.46	7.57	9.72	ns
		XC6SLX75T	5.94	6.46	7.57	N/A	ns
		XC6SLX100	6.09	6.53	7.60	9.66	ns
		XC6SLX100T	6.09	6.53	7.60	N/A	ns
		XC6SLX150	6.29	6.69	7.81	9.94	ns
		XC6SLX150T	6.29	6.69	7.81	N/A	ns
		XA6SLX4	5.83	N/A	6.95	N/A	ns
		XA6SLX9	5.83	N/A	6.95	N/A	ns
		XA6SLX16	5.65	N/A	6.68	N/A	ns
		XA6SLX25	5.85	N/A	7.03	N/A	ns
		XA6SLX25T	5.85	N/A	7.03	N/A	ns
		XA6SLX45	6.07	N/A	7.25	N/A	ns
		XA6SLX45T	6.07	N/A	7.25	N/A	ns
		XA6SLX75	6.26	N/A	7.57	N/A	ns
		XA6SLX75T	6.26	N/A	7.57	N/A	ns
		XA6SLX100	N/A	N/A	7.48	N/A	ns
		XQ6SLX75	N/A	N/A	7.57	9.72	ns
		XQ6SLX75T	6.26	N/A	7.57	N/A	ns
		XQ6SLX150	N/A	N/A	7.81	9.94	ns
		XQ6SLX150T	6.62	N/A	7.81	N/A	ns

Date	Version	Description of Revisions
09/14/11	2.4	Production release of the XA6SLX4 and XA6SLX9 devices in Table 26 and Table 27 using ISE v13.2 software with -2 and -3 speed specification v1.19. Added production released version of the XA6SLX100 to Table 26 and Table 27 using ISE v13.3 software with -2 speed specification v1.20. Updated R_{OUT_TERM} description in Table 4. Fixed the LVPECL V_H error in Table 31. Updated introduction in Simultaneously Switching Outputs. Added the XA6SLX100 to Table 63 through Table 78, and Table 81. Added Note 4 to Table 78 because the T_{CKSKEW} for the XC6SLX100 is not the same as the T_{CKSKEW} for the XA6SLX100. Revised the revision history for version 1.6 dated 06/24/10. Removed the parenthetical statement about the -3N speed grade: (specifications are identical to the -3 speed grade).
10/17/11	3.0	Changed the data sheet from Preliminary Product Specification to Product Specification. Updated the Switching Characteristics, page 19 speed specification version ISE v13.3 software to -2 and -3 speed specification v1.20 and -1L speed specification of v1.08. Also updated Note 1 in Table 27. In Table 43, <i>Block RAM Switching Characteristics</i>, the F_{MAX} value for the -2 speed grade has been changed from 260 MHz to 280 MHz. In Table 54, <i>Switching Characteristics for the DLL</i>, a Note 6 was added and linked to CLKIN_CLKFB_PHASE.